NSN 5961-00-078-6878

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-078-6878 **Inclosure Material:** Metal **Overall Length:** Between 12.190 inches and 12.310 inches Overall Diameter: 1.900 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 70000.0 reverse voltage, peak **Current Rating Per Characteristic:** 4.00 amperes source cutoff current preset and 50.00 amperes source cutoff current outside diameter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** End contact length 0.50 in. Min for anode and 07.0 in. Min for cathode; assembly outer diameter 1.90 in. **Test Data Document:** 97942-128c548 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: